

Plastic-Encapsulate Diodes

High Speed Switching Diode

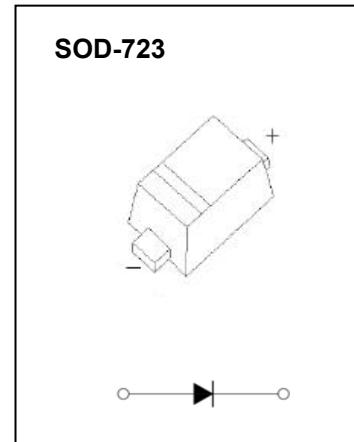
FEATURES

- Small surface mounting type
- High speed
- High reliability with high surge current handing capability

MARKING:A



The marking bar indicates the cathode



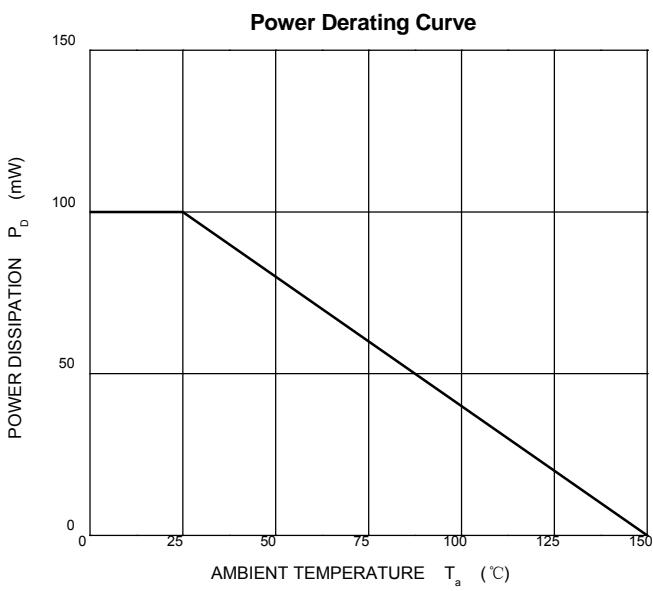
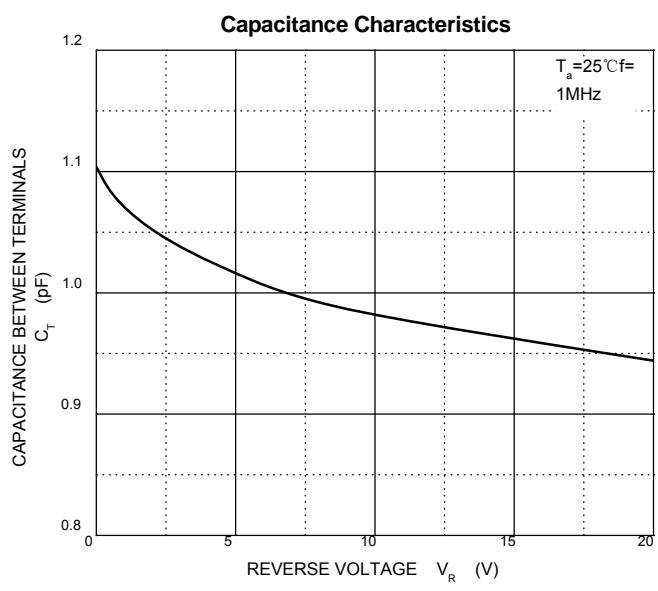
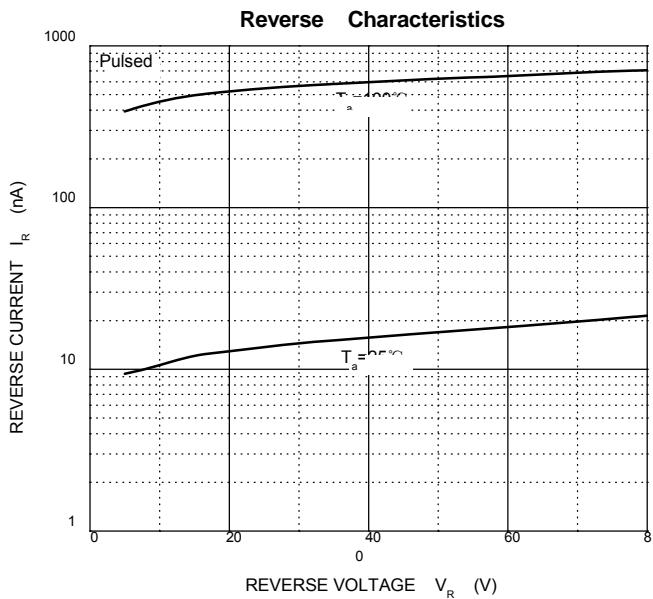
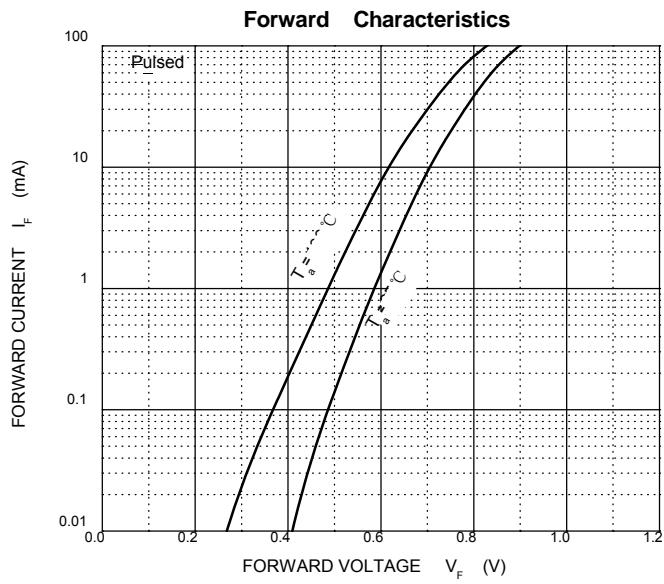
Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C

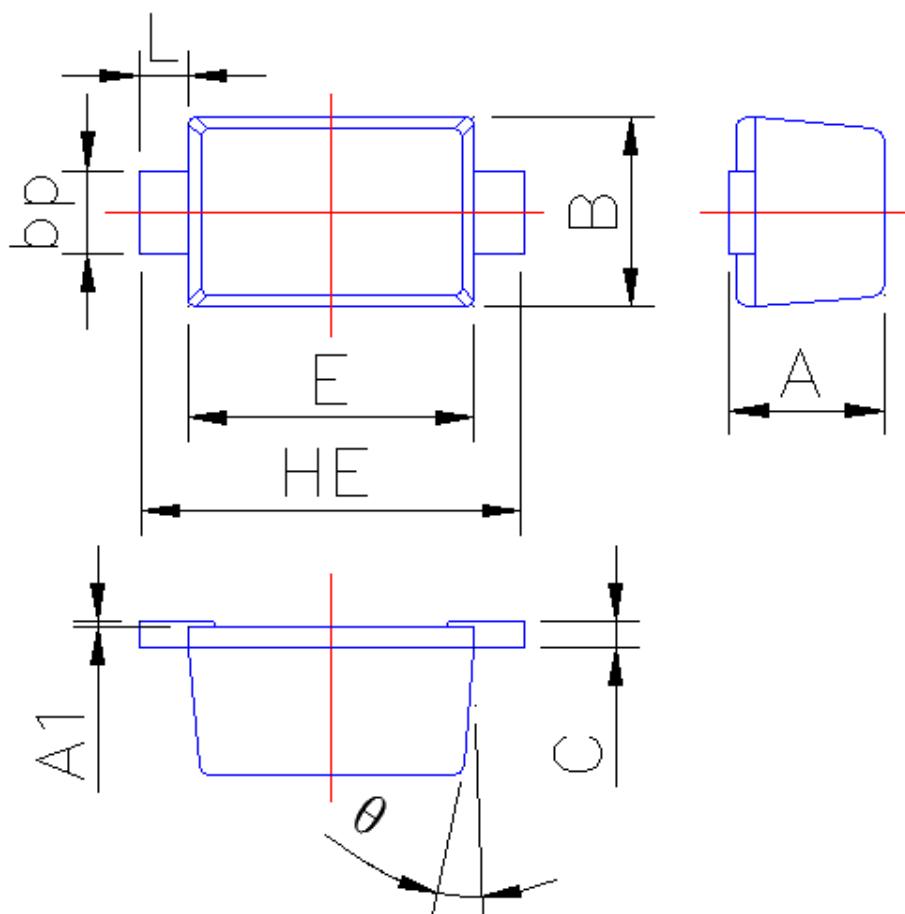
Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	V _{RM}	90	V
DC Blocking Voltage	V _R	80	V
Forward Continuous Current	I _{FM}	225	mA
Average Rectified Output Current	I _O	100	mA
Non-Repetitive Peak Forward Surge Current @ t=8.3ms	I _{FSM}	2.0	A
Power Dissipation	P _d	100	mW
Thermal Resistance Junction to Ambient	R _{θJA}	1250	°C/W
Operation Junction and Storage Temperature Range	T _J , T _{STG}	-55~+150	°C

Electrical Ratings @Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	V _F			1.2	V	I _F =100mA
Reverse current	I _R			0.1	µA	V _R =80V
Capacitance between terminals	C _T			3.0	pF	V _R =0.5V, f=1MHZ
Reverse recovery time	t _{rr}			4	ns	V _R =6V, I _F =10mA, R _L =100Ω

Typical Characteristics



SOD-723-Package Outline Dimensions


Symbol	Dimension in Millimeters	
	Min	Max
A	0.515	0.580
A1	0.010	0.070
B	0.550	0.650
bp	0.250	0.350
C	0.08	0.150
E	0.900	1.100
HE	1.30	1.50
L	0.150	0.250
θ	7°	